

LMH6639

190MHz Rail-to-Rail Output Amplifier with Disable

General Description

The LMH6639 is a voltage feedback operational amplifier with a rail-to-rail output drive capability of 110mA. Employing National's patented VIP10 process, the LMH6639 delivers a bandwidth of 190MHz at a current consumption of only 3.6mA. An input common mode voltage range extending to 0.2V below the V^- and to within 1V of V^+ , makes the LMH6639 a true single supply op-amp. The output voltage range extends to within 30mV of either supply rail providing the user with a dynamic range that is especially desirable in low voltage applications.

The LMH6639 offers a slew rate of 172V/ μ s resulting in a full power bandwidth of approximately 28MHz. The T_{ON} value of 83nsec combined with a settling time of 33nsec makes this device ideally suited for multiplexing applications. Careful attention has been paid to ensure device stability under all operating voltages and modes. The result is a very well behaved frequency response characteristic for any gain setting including +1, and excellent specifications for driving video cables including harmonic distortion of -60dBc, differential gain of 0.12% and differential phase of 0.045°

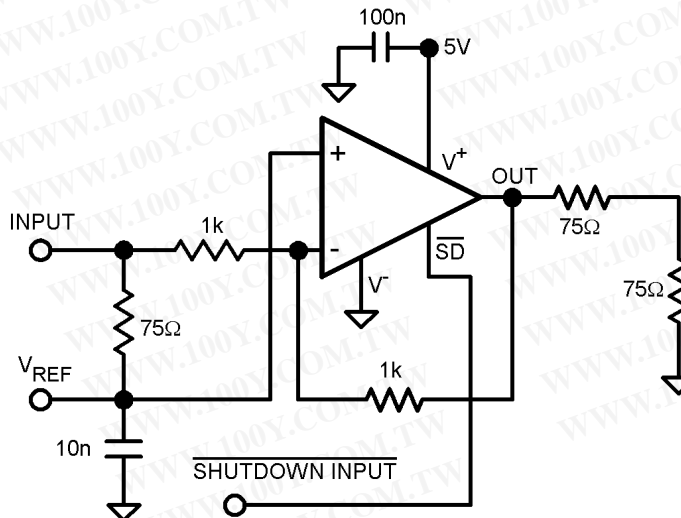
Features

($V_S = 5V$, Typical values unless specified)

■ Supply current (no load)	3.6mA
■ Supply current (off mode)	400 μ A
■ Output resistance (closed loop 1MHz)	0.186 Ω
■ -3dB BW ($A_V = 1$)	190MHz
■ Settling time	33nsec
■ Input common mode voltage	-0.2V to 4V
■ Output voltage swing	40mV from rails
■ Linear output current	110mA
■ Total harmonic distortion	-60dBc
■ Fully characterized for 3V, 5V and $\pm 5V$	
■ No output phase reversal with CMVR exceeded	
■ Excellent overdrive recovery	
■ Off Isolation 1MHz	-70dB
■ Differential Gain	0.12%
■ Differential Phase	0.045°

Applications

- Active filters
- CD/DVD ROM
- ADC buffer amplifier
- Portable video
- Current sense buffer



20030246

FIGURE 1. Typical Single Supply Schematic

Absolute Maximum Ratings (Note 1)

If Military/Aerospace specified devices are required, please contact the National Semiconductor Sales Office/Distributors for availability and specifications.

ESD Tolerance	2KV (Note 2)
	200V (Note 9)
V_{IN} Differential	$\pm 2.5V$
Input Current	$\pm 10mA$
Supply Voltage ($V^+ - V^-$)	13.5V
Voltage at Input/Output pins	$V^+ + 0.8V, V^- - 0.8V$
Storage Temperature Range	$-65^\circ C$ to $+150^\circ C$

Junction Temperature (Note 4)	$+150^\circ C$
Soldering Information	
Infrared or Convection (20 sec)	$235^\circ C$
Wave Soldering (10 sec)	$260^\circ C$

Operating Ratings (Note 1)

Operating Temperature Range (Note 4)	$-40^\circ C$ to $+85^\circ C$
Package Thermal Resistance (θ_{JA}) (Note 4)	
SOT23-6	$265^\circ C/W$
SOIC-8	$190^\circ C/W$

3V Electrical Characteristics

Unless otherwise specified, all limits guaranteed for at $T_J = 25^\circ C$, $V^+ = 3V$, $V^- = 0V$, $V_O = V_{CM} = V^+/2$, and $R_L = 2k\Omega$ to $V^+/2$. **Boldface** limits apply at the temperature extremes.

Symbol	Parameter	Conditions	Min (Note 6)	Typ (Note 5)	Max (Note 6)	Units
BW	-3dB BW	$A_V = +1$	120	170		MHz
		$A_V = -1$		63		
$BW_{0.1dB}$	0.1dB Gain Flatness	$R_F = 2.65k\Omega, R_L = 1k\Omega,$		16.4		MHz
FPBW	Full Power Bandwidth	$A_V = +1, V_{OUT} = 2V_{PP}, -1dB$ $V^+ = 1.8V, V^- = 1.2V$		21		MHz
GBW	Gain Bandwidth product	$A_V = +1$		83		MHz
e_n	Input-Referred Voltage Noise	$R_F = 33k\Omega$	$f = 10kHz$	19		nV/\sqrt{Hz}
			$f = 1MHz$	16		
i_n	Input-Referred Current Noise	$R_F = 1M\Omega$	$f = 10kHz$	1.30		pA/\sqrt{Hz}
			$f = 1MHz$	0.36		
THD	Total Harmonic Distortion	$f = 5MHz, V_O = 2V_{PP}, A_V = +2,$ $R_L = 1k\Omega$ to $V^+/2$		-50		dBc
T_S	Settling Time	$V_O = 2V_{PP}, \pm 0.1\%$		37		ns
SR	Slew Rate	$A_V = -1$ (Note 8)	120	167		V/ μs
V_{OS}	Input Offset Voltage			1.01	5 7	mV
TC V_{OS}	Input Offset Average Drift	(Note 11)		8		$\mu V/^\circ C$
I_B	Input Bias Current	(Note 7)		-1.02	-2.6 -3.5	μA
I_{OS}	Input Offset Current			20	800 1000	nA
R_{IN}	Common Mode Input Resistance	$A_V = +1, f = 1kHz, R_S = 1M\Omega$		6.1		M Ω
C_{IN}	Common Mode Input Capacitance	$A_V = +1, R_S = 100k\Omega$		1.35		pF
CMVR	Input Common-Mode Voltage Range	CMRR $\geq 50dB$		-0.3	-0.2 -0.1	V
			1.8 1.6	2		
CMRR	Common Mode Rejection Ratio	(Note 12)	72	93		dB
A_{VOL}	Large Signal Voltage Gain	$V_O = 2V_{PP}, R_L = 2k\Omega$ to $V^+/2$	80 76	100		dB
		$V_O = 2V_{PP}, R_L = 150\Omega$ to $V^+/2$	74 70	78		

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3V Electrical Characteristics (Continued)

Unless otherwise specified, all limits guaranteed for at $T_J = 25^\circ\text{C}$, $V^+ = 3\text{V}$, $V^- = 0\text{V}$, $V_O = V_{\text{CM}} = V^+/2$, and $R_L = 2\text{k}\Omega$ to $V^+/2$. **Boldface** limits apply at the temperature extremes.

Symbol	Parameter	Conditions	Min (Note 6)	Typ (Note 5)	Max (Note 6)	Units
V_O	Output Swing High	$R_L = 2\text{k}\Omega$ to $V^+/2$, $V_{\text{ID}} = 200\text{mV}$	2.90	2.98		V
		$R_L = 150\Omega$ to $V^+/2$, $V_{\text{ID}} = 200\text{mV}$	2.75	2.93		
		$R_L = 50\Omega$ to $V^+/2$, $V_{\text{ID}} = 200\text{mV}$	2.6	2.85		
	Output Swing Low	$R_L = 2\text{k}\Omega$ to $V^+/2$, $V_{\text{ID}} = -200\text{mV}$		25	75	mV
		$R_L = 150\Omega$ to $V^+/2$, $V_{\text{ID}} = -200\text{mV}$		75	200	
		$R_L = 50\Omega$ to $V^+/2$, $V_{\text{ID}} = -200\text{mV}$		130	300	
I_{SC}	Output Short Circuit Current	Sourcing to $V^+/2$, (Note 10)	50 35	120		mA
		Sinking to $V^+/2$, (Note 10)	67 40	140		
I_{OUT}	Output Current	$V_O = 0.5\text{V}$ from either supply		99		mA
PSRR	Power Supply Rejection Ratio	(Note 12)	72	96		dB
I_S	Supply Current (Enabled)	No Load		3.5	5.6 7.5	mA
	Supply Current (Disabled)			0.3	0.5 0.7	
TH_SD	Threshold Voltage for Shutdown Mode			$V^+ - 1.59$		V
$I_{\text{SD PIN}}$	Shutdown Pin Input Current	SD Pin Connect to 0V (Note 7)		-13		μA
T_{ON}	On Time After Shutdown			83		nsec
T_{OFF}	Off Time to Shutdown			160		nsec
R_{OUT}	Output Resistance Closed Loop	$R_F = 10\text{k}\Omega$, $f = 1\text{kHz}$, $A_V = -1$		27		m Ω
		$R_F = 10\text{k}\Omega$, $f = 1\text{MHz}$, $A_V = -1$		266		

5V Electrical Characteristics

Unless otherwise specified, all limits guaranteed for at $T_J = 25^\circ\text{C}$, $V^+ = 5\text{V}$, $V^- = 0\text{V}$, $V_O = V_{\text{CM}} = V^+/2$, and $R_L = 2\text{k}\Omega$ to $V^+/2$. **Boldface** limits apply at the temperature extremes.

Symbol	Parameter	Conditions	Min (Note 6)	Typ (Note 5)	Max (Note 6)	Units
BW	-3dB BW	$A_V = +1$	130	190		MHz
		$A_V = -1$		64		
$BW_{0.1\text{dB}}$	0.1dB Gain Flatness	$R_F = 2.51\text{k}\Omega$, $R_L = 1\text{k}\Omega$,		16.4		MHz
FPBW	Full Power Bandwidth	$A_V = +1$, $V_{\text{OUT}} = 2V_{\text{PP}}$, -1dB		28		MHz
GBW	Gain Bandwidth Product	$A_V = +1$		86		MHz
e_n	Input-Referred Voltage Noise	$R_F = 33\text{k}\Omega$	$f = 10\text{kHz}$	19		nV/ $\sqrt{\text{Hz}}$
			$f = 1\text{MHz}$	16		
i_n	Input-Referred Current Noise	$R_F = 1\text{M}\Omega$	$f = 10\text{kHz}$	1.35		pA/ $\sqrt{\text{Hz}}$
			$f = 1\text{MHz}$	0.35		
THD	Total Harmonic Distortion	$f = 5\text{MHz}$, $V_O = 2V_{\text{PP}}$, $A_V = +2$ $R_L = 1\text{k}\Omega$ to $V^+/2$		-60		dBc
DG	Differential Gain	NTSC, $A_V = +2$ $R_L = 150\Omega$ to $V^+/2$		0.12		%
DP	Differential Phase	NTSC, $A_V = +2$ $R_L = 150\Omega$ to $V^+/2$		0.045		deg
T_S	Settling Time	$V_O = 2V_{\text{PP}}$, $\pm 0.1\%$		33		ns
SR	Slew Rate	$A_V = -1$, (Note 8)	130	172		V/ μs
V_{OS}	Input Offset Voltage			1.02	5 7	mV

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5V Electrical Characteristics (Continued)

Unless otherwise specified, all limits guaranteed for at $T_J = 25^\circ\text{C}$, $V^+ = 5\text{V}$, $V^- = 0\text{V}$, $V_O = V_{CM} = V^+/2$, and $R_L = 2\text{k}\Omega$ to $V^+/2$.

Boldface limits apply at the temperature extremes.

Symbol	Parameter	Conditions	Min (Note 6)	Typ (Note 5)	Max (Note 6)	Units
TC V_{OS}	Input Offset Average Drift	(Note 11)		8		$\mu\text{V}/^\circ\text{C}$
I_B	Input Bias Current	(Note 7)		-1.2	-2.6 -3.25	μA
I_{OS}	Input Offset Current			20	800 1000	nA
R_{IN}	Common Mode Input Resistance	$A_V = +1$, $f = 1\text{kHz}$, $R_S = 1\text{M}\Omega$		6.88		$\text{M}\Omega$
C_{IN}	Common Mode Input Capacitance	$A_V = +1$, $R_S = 100\text{k}\Omega$		1.32		pF
CMVR	Common-Mode Input Voltage Range	CMRR $\geq 50\text{dB}$		-0.3	-0.2 -0.1	V
				4	3.8 3.6	
CMRR	Common Mode Rejection Ratio	(Note 12)	72	95		dB
A_{VOL}	Large Signal Voltage Gain	$V_O = 4V_{PP}$ $R_L = 2\text{k}\Omega$ to $V^+/2$	86 82	100		dB
		$V_O = 3.75V_{PP}$ $R_L = 150\Omega$ to $V^+/2$	74 70	77		
V_O	Output Swing High	$R_L = 2\text{k}\Omega$ to $V^+/2$, $V_{ID} = 200\text{mV}$	4.90	4.97		V
		$R_L = 150\Omega$ to $V^+/2$, $V_{ID} = 200\text{mV}$	4.65	4.90		
		$R_L = 50\Omega$ to $V^+/2$, $V_{ID} = 200\text{mV}$	4.40	4.77		
V_O	Output Swing Low	$R_L = 2\text{k}\Omega$ to $V^+/2$, $V_{ID} = -200\text{mV}$		25	100	mV
		$R_L = 150\Omega$ to $V^+/2$, $V_{ID} = -200\text{mV}$		85	200	
		$R_L = 50\Omega$ to $V^+/2$, $V_{ID} = -200\text{mV}$		190	400	
I_{SC}	Output Short Circuit Current	Sourcing to $V^+/2$, (Note 10)	100 79	160		mA
		Sinking from $V^+/2$, (Note 10)	120 85	190		
I_{OUT}	Output Current	$V_O = 0.5\text{V}$ from either supply		110		mA
PSRR	Power Supply Rejection Ratio	(Note 12)	72	96		dB
I_S	Supply Current (Enabled)	No Load		3.6	5.8 8.0	mA
	Supply Current (Disabled)			0.40	0.8 1.0	
TH_SD	Threshold Voltage for Shutdown Mode			$V^+ - 1.65$		V
$I_{SD\text{ PIN}}$	Shutdown Pin Input Current	SD Pin Connected to 0V (Note 7)		-30		μA
T_{ON}	On Time after Shutdown			83		nsec
T_{OFF}	Off Time to Shutdown			160		nsec
R_{OUT}	Output Resistance Closed Loop	$R_F = 10\text{k}\Omega$, $f = 1\text{kHz}$, $A_V = -1$		29		m Ω
		$R_F = 10\text{k}\Omega$, $f = 1\text{MHz}$, $A_V = -1$		253		

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±5V Electrical Characteristics

Unless otherwise specified, all limits guaranteed for at $T_J = 25^\circ\text{C}$, $V_{\text{SUPPLY}} = \pm 5\text{V}$, $V_O = V_{\text{CM}} = \text{GND}$, and $R_L = 2\text{k}\Omega$ to $V^+/2$. **Boldface** limits apply at the temperature extremes.

Symbol	Parameter	Conditions	Min (Note 6)	Typ (Note 5)	Max (Note 6)	Units
BW	-3dB BW	$A_V = +1$	150	228		MHz
		$A_V = -1$		65		
$BW_{0.1\text{dB}}$	0.1dB Gain Flatness	$R_F = 2.26\text{k}\Omega$, $R_L = 1\text{k}\Omega$		18		MHz
FPBW	Full Power Bandwidth	$A_V = +1$, $V_{\text{OUT}} = 2V_{\text{PP}}$, -1dB		29		MHz
GBW	Gain Bandwidth Product	$A_V = +1$		90		MHz
e_n	Input-Referred Voltage Noise	$R_F = 33\text{k}\Omega$	$f = 10\text{kHz}$	19		$\text{nV}/\sqrt{\text{Hz}}$
			$f = 1\text{MHz}$	16		
i_n	Input-Referred Current Noise	$R_F = 1\text{M}\Omega$	$f = 10\text{kHz}$	1.13		$\text{pA}/\sqrt{\text{Hz}}$
			$f = 1\text{MHz}$	0.34		
THD	Total Harmonic Distortion	$f = 5\text{MHz}$, $V_O = 2V_{\text{PP}}$, $A_V = +2$, $R_L = 1\text{k}\Omega$		-71.2		dBc
DG	Differential Gain	NTSC, $A_V = +2$ $R_L = 150\Omega$		0.11		%
DP	Differential Phase	NTSC, $A_V = +2$ $R_L = 150\Omega$		0.053		deg
T_S	Settling Time	$V_O = 2V_{\text{PP}}$, $\pm 0.1\%$		33		ns
SR	Slew Rate	$A_V = -1$ (Note 8)	140	200		$\text{V}/\mu\text{s}$
V_{OS}	Input Offset Voltage			1.03	5	mV
				7		
TC V_{OS}	Input Offset Voltage Drift	(Note 11)		8		$\mu\text{V}/^\circ\text{C}$
I_B	Input Bias Current	(Note 7)		-1.40	-2.6 -3.25	μA
I_{OS}	Input Offset Current			20	800 1000	nA
R_{IN}	Common Mode Input Resistance	$A_V +1$, $f = 1\text{kHz}$, $R_S = 1\text{M}\Omega$		7.5		$\text{M}\Omega$
C_{IN}	Common Mode Input Capacitance	$A_V = +1$, $R_S = 100\text{k}\Omega$		1.28		pF
CMVR	Common Mode Input Voltage Range	CMRR $\geq 50\text{dB}$		-5.3	-5.2 -5.1	V
			3.8 3.6	4.0		
CMRR	Common Mode Rejection Ratio	(Note 12)	72	95		dB
A_{VOL}	Large Signal Voltage Gain	$V_O = 9V_{\text{PP}}$, $R_L = 2\text{k}\Omega$	88 84	100		dB
		$V_O = 8V_{\text{PP}}$, $R_L = 150\Omega$	74 70	77		
V_O	Output Swing High	$R_L = 2\text{k}\Omega$, $V_{\text{ID}} = 200\text{mV}$	4.85	4.96		V
		$R_L = 150\Omega$, $V_{\text{ID}} = 200\text{mV}$	4.55	4.80		
		$R_L = 50\Omega$, $V_{\text{ID}} = 200\text{mV}$	3.60	4.55		
	Output Swing Low	$R_L = 2\text{k}\Omega$, $V_{\text{ID}} = -200\text{mV}$		-4.97	-4.90	V
		$R_L = 150\Omega$, $V_{\text{ID}} = -200\text{mV}$		-4.85	-4.55	
		$R_L = 50\Omega$, $V_{\text{ID}} = -200\text{mV}$		-4.65	-4.30	
I_{SC}	Output Short Circuit Current	Sourcing to Ground, (Note 10)	100 80	168		mA
		Sinking to Ground, (Note 10)	110 85	190		

±5V Electrical Characteristics (Continued)

Unless otherwise specified, all limits guaranteed for at $T_J = 25^\circ\text{C}$, $V_{\text{SUPPLY}} = \pm 5\text{V}$, $V_O = V_{\text{CM}} = \text{GND}$, and $R_L = 2\text{k}\Omega$ to $V^+/2$.

Boldface limits apply at the temperature extremes.

Symbol	Parameter	Conditions	Min (Note 6)	Typ (Note 5)	Max (Note 6)	Units
I_{OUT}	Output Current	$V_O = 0.5\text{V}$ from either supply		112		mA
PSRR	Power Supply Rejection Ratio	(Note 12)	72	96		dB
I_S	Supply Current (Enabled)	No Load		4.18	6.5	mA
	Supply Current (Disabled)			0.758	1.0 1.3	
TH_SD	Threshold Voltage for Shutdown Mode			$V^+ - 1.67$		V
$I_{\text{SD PIN}}$	Shutdown Pin Input Current	SD Pin Connected to -5V (Note 7)		-84		μA
T_{ON}	On Time after Shutdown			83		nsec
T_{OFF}	Off Time to Shutdown			160		nsec
R_{OUT}	Output Resistance Closed Loop	$R_F = 10\text{k}\Omega$, $f = 1\text{kHz}$, $A_V = -1$		32		m Ω
		$R_F = 10\text{k}\Omega$, $f = 1\text{MHz}$, $A_V = -1$		226		

Note 1: Absolute Maximum Ratings indicate limits beyond which damage to the device may occur. Operating Ratings indicate conditions for which the device is intended to be functional, but specific performance is not guaranteed. For guaranteed specifications and the test conditions, see the Electrical Characteristics.

Note 2: Human body model, $1.5\text{k}\Omega$ in series with 100pF .

Note 3: Applies to both single-supply and split-supply operation. Continuous short circuit operation at elevated ambient temperature can result in exceeding the maximum allowed junction temperature of 150°C .

Note 4: The maximum power dissipation is a function of $T_{\text{J(MAX)}}$, θ_{JA} , and T_A . The maximum allowable power dissipation at any ambient temperature is $P_D = (T_{\text{J(MAX)}} - T_A) / \theta_{\text{JA}}$. All numbers apply for packages soldered directly onto a PC board.

Note 5: Typical values represent the most likely parametric norm.

Note 6: All limits are guaranteed by testing or statistical analysis.

Note 7: Positive current corresponds to current flowing into the device.

Note 8: Slew rate is the average of the rising and falling slew rates.

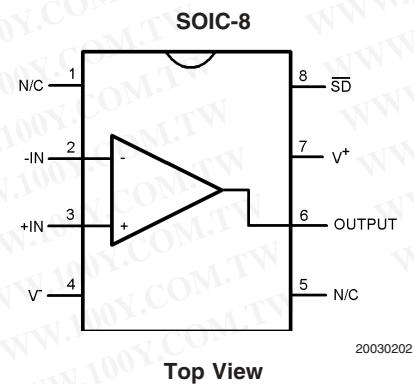
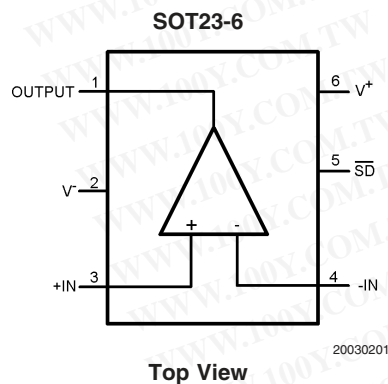
Note 9: Machine Model, 0Ω in series with 200pF .

Note 10: Short circuit test is a momentary test.

Note 11: Offset voltage average drift determined by dividing the change in V_{OS} at temperature extremes into the total temperature change.

Note 12: $f \leq 1\text{kHz}$ (see typical performance Characteristics)

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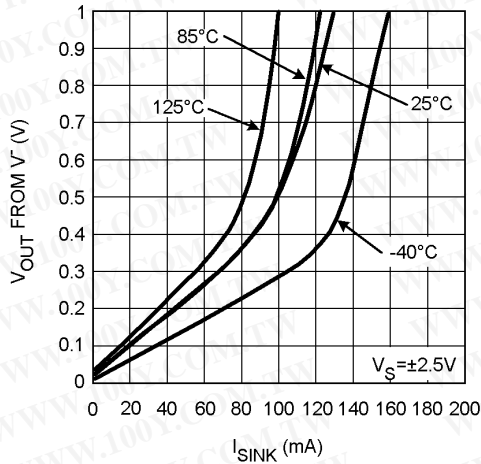
Connection Diagrams**Ordering Information**

Package	Part Number	Package Marking	Transport Media	NSC Drawing
6-Pin SOT-23	LMH6639MF	A81A	1k Units Tape and Reel	MF06A
	LMH6639MFX		3k Units Tape and Reel	
8-Pin SOIC	LMH6639MA	LMH6639MA	Rails	M08A
	LMH6639MAX		2.5k Units Tape and Reel	

Typical Performance Characteristics

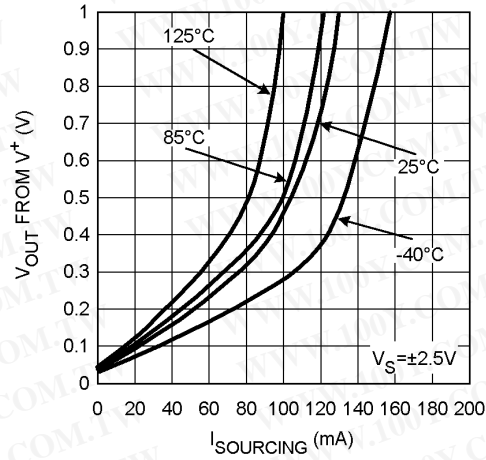
At $T_J = 25^\circ\text{C}$, $V^+ = +2.5\text{V}$, $V^- = -2.5\text{V}$, $R_F = 330\Omega$ for $A_V = +2$, $R_F = 1\text{k}\Omega$ for $A_V = -1$. Unless otherwise specified.

Output Sinking Saturation Voltage vs. I_{OUT} for Various Temperature



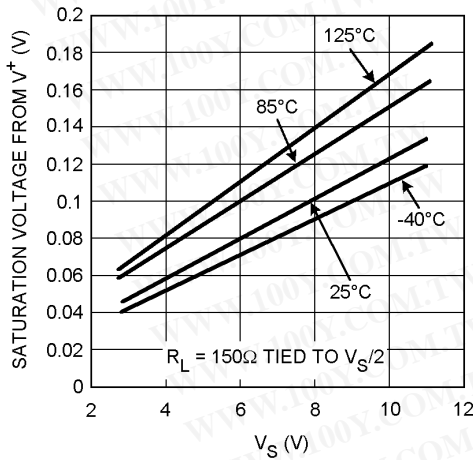
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Output Sourcing Saturation Voltage vs. I_{OUT} for Various Temperature



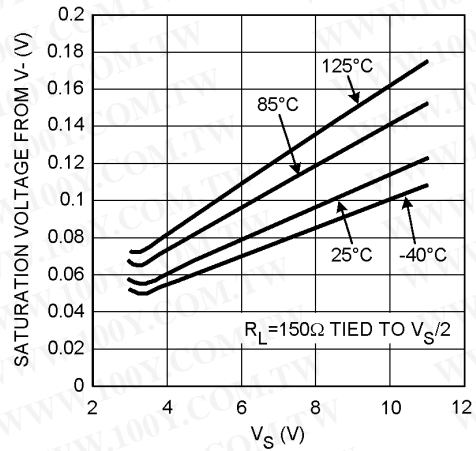
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Positive Output Saturation Voltage vs. V_{SUPPLY} for Various Temperature



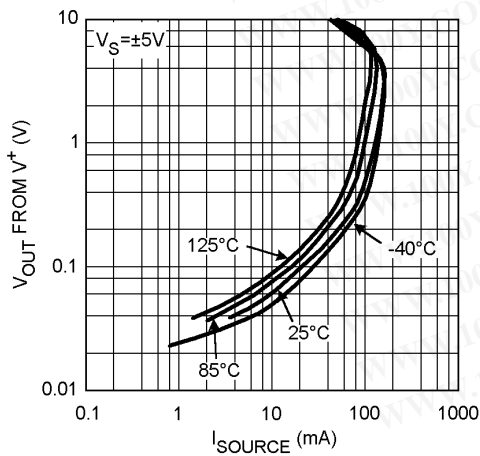
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Negative Output Saturation Voltage vs. V_{SUPPLY} for Various Temperature



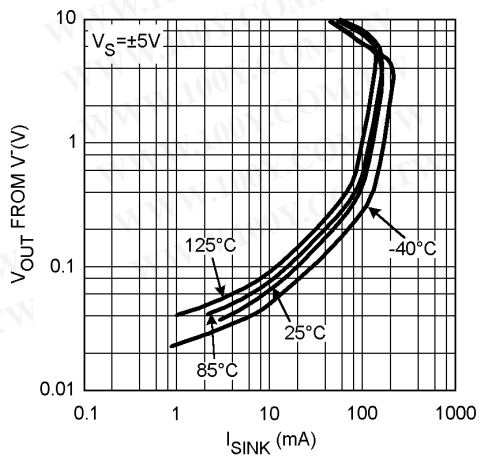
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V_{OUT} from V^+ vs. I_{SOURCE}



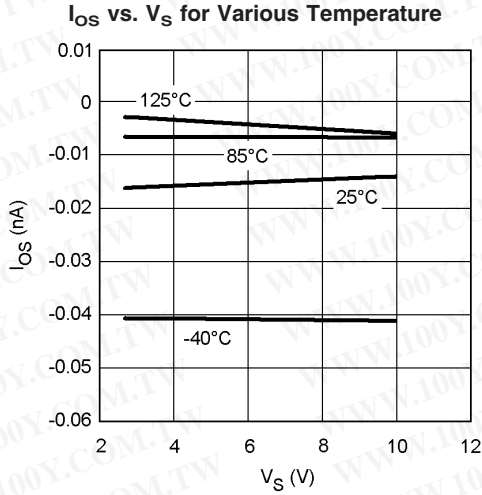
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V_{OUT} from V^- vs. I_{SINK}

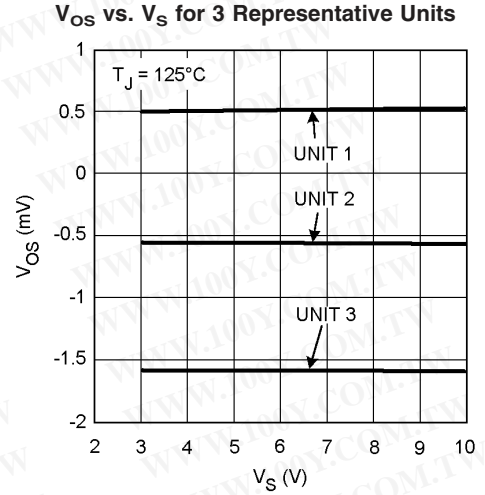


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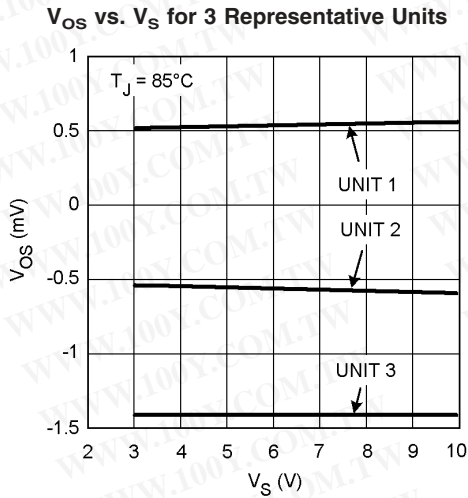
Typical Performance Characteristics At $T_J = 25^\circ\text{C}$, $V^+ = +2.5\text{V}$, $V^- = -2.5\text{V}$, $R_F = 330\Omega$ for $A_V = +2$, $R_F = 1\text{k}\Omega$ for $A_V = -1$. Unless otherwise specified. (Continued)



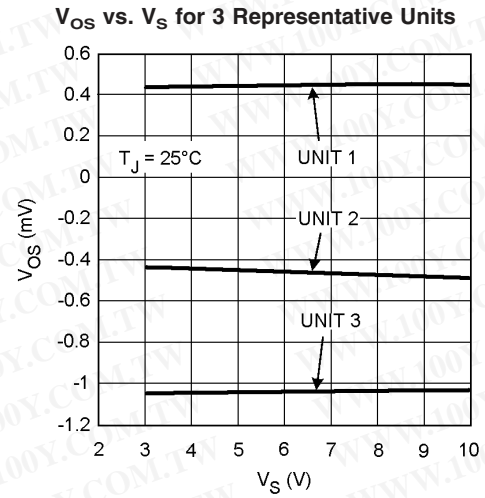
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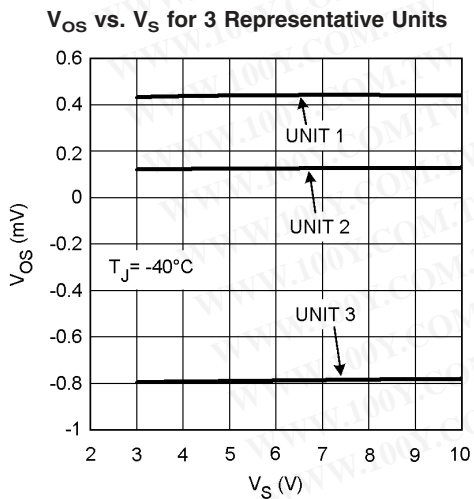
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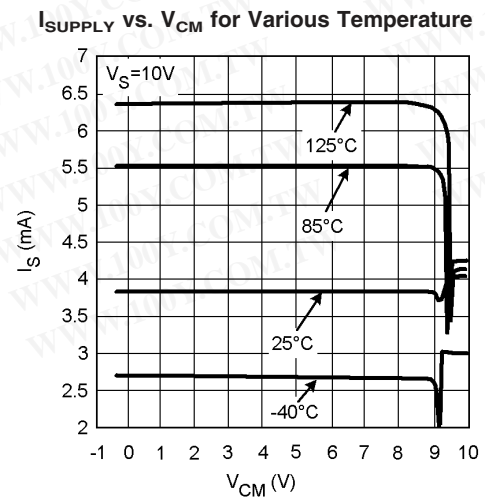
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20030243



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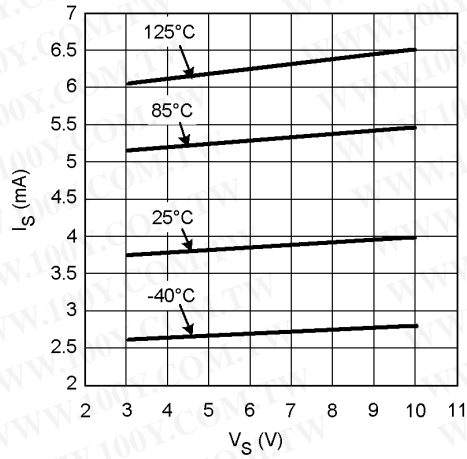


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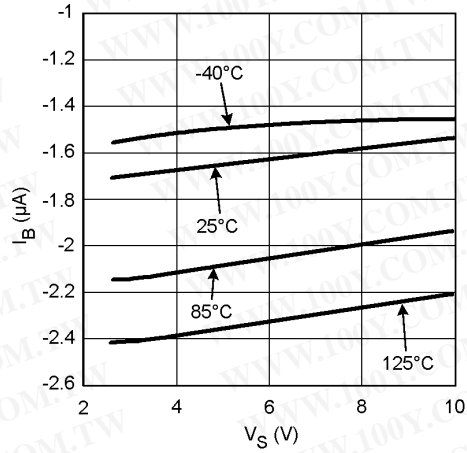
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I_{SUPPLY} vs. V_S for Various Temperature



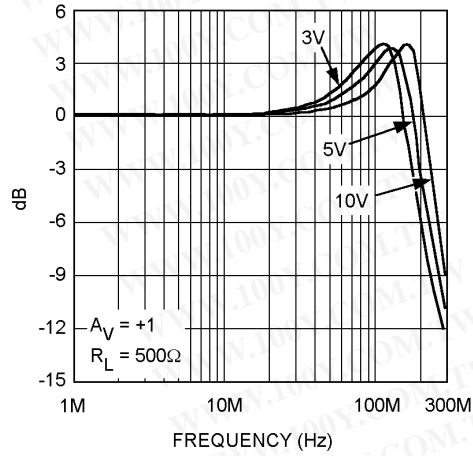
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I_B vs. V_S for Various Temperature



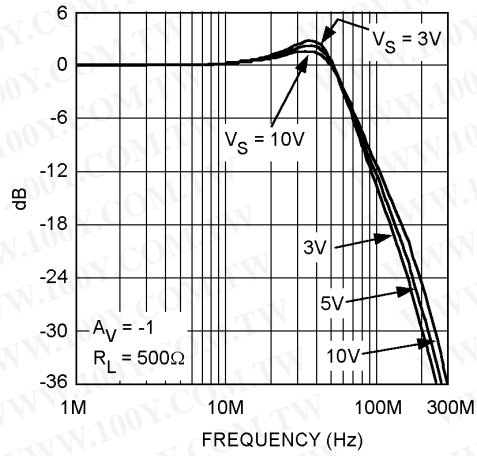
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Bandwidth for Various V_S



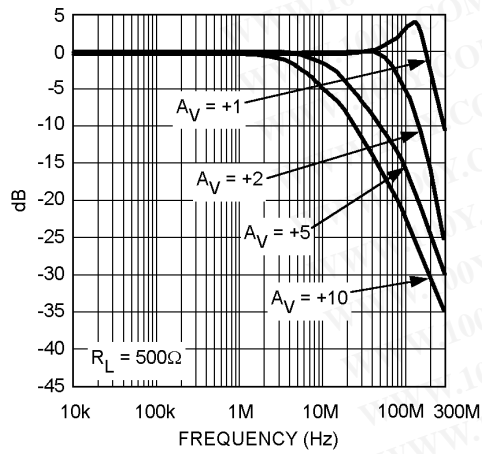
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Bandwidth for Various V_S



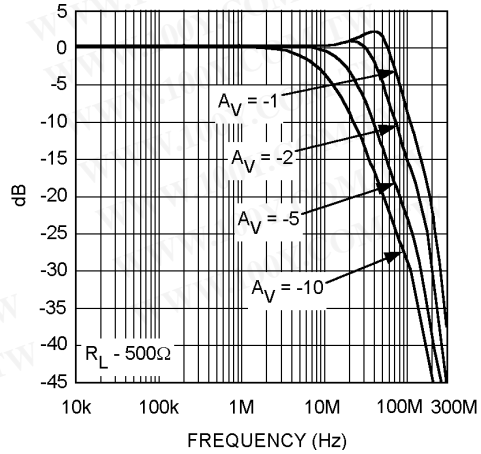
20030205

Gain vs. Frequency Normalized



20030207

Gain vs. Frequency Normalized

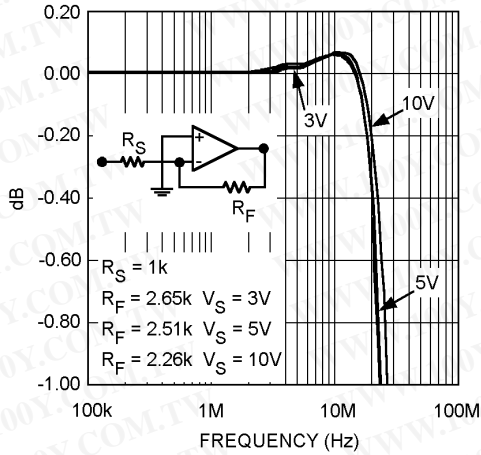


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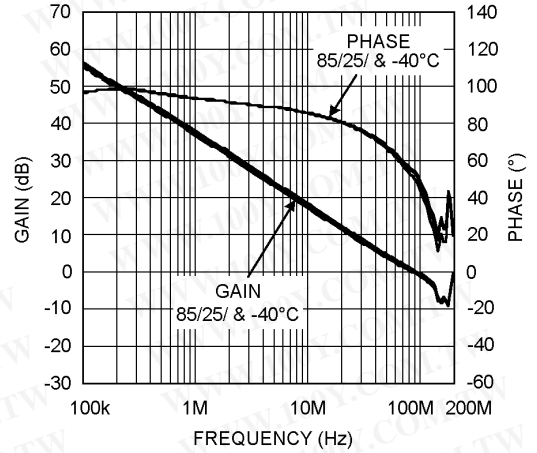
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0.1dB Gain Flatness



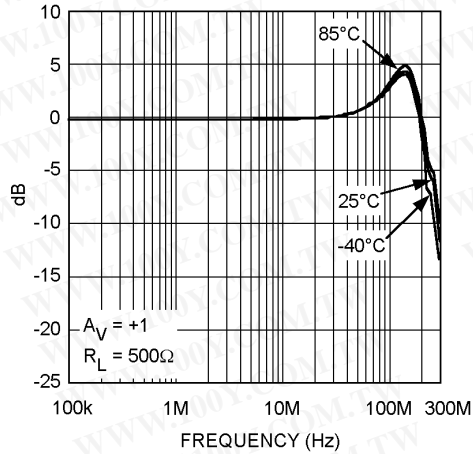
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Gain and phase vs. Frequency for Various Temperature



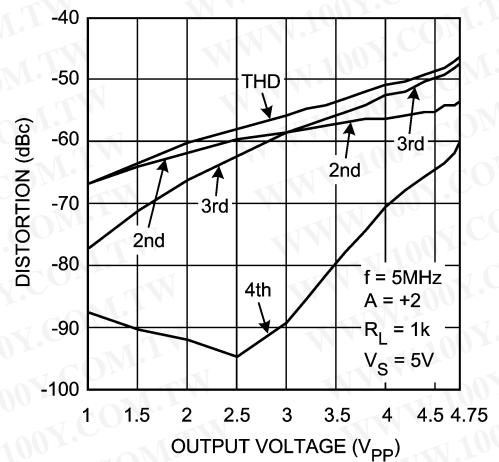
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Frequency Response vs. Temperature



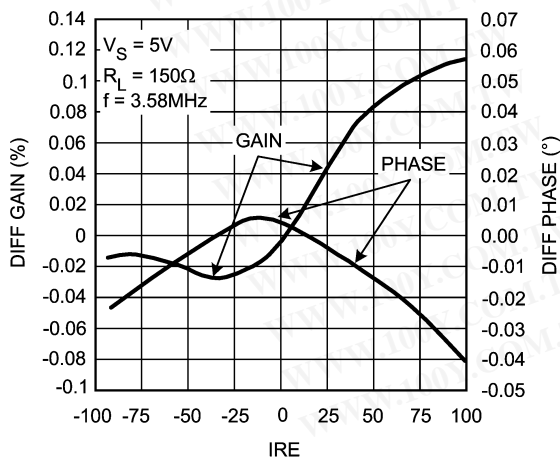
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Harmonic Distortion



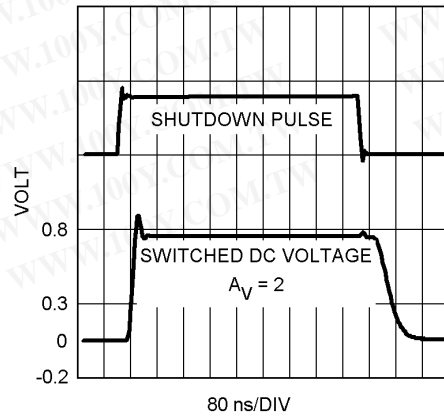
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Differential Gain/Phase



20030270

On-Off Switching DC Voltage

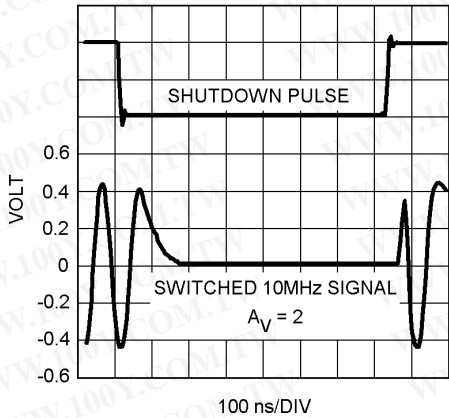


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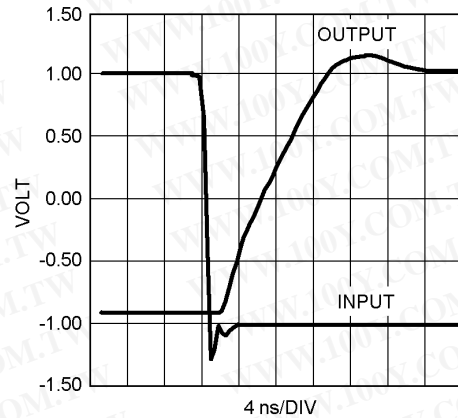
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On-Off Switching 10MHz



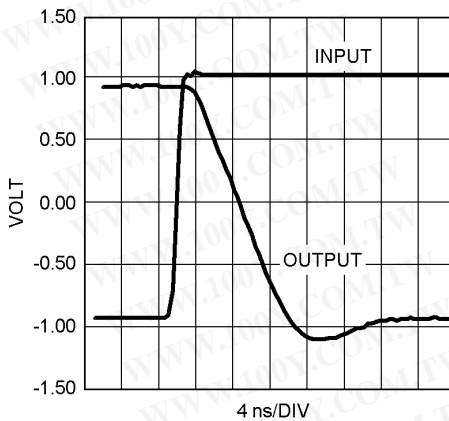
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Slew Rate (Positive)



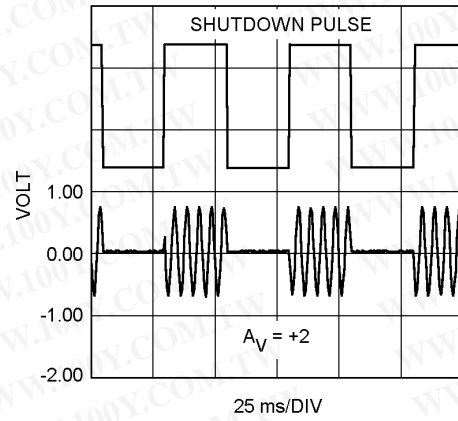
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Slew Rate (Negative)



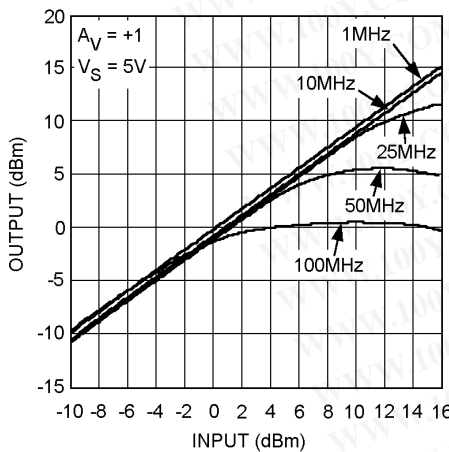
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On-Off Switching of Sinewave



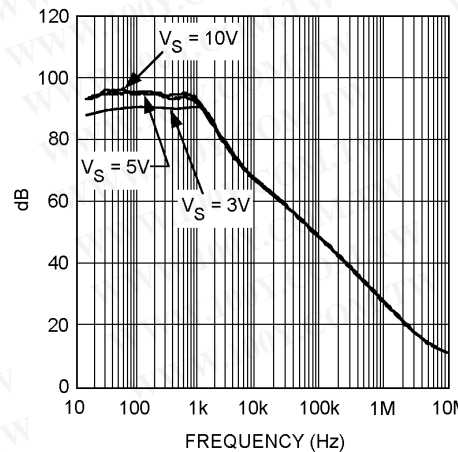
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Power Sweep



20030216

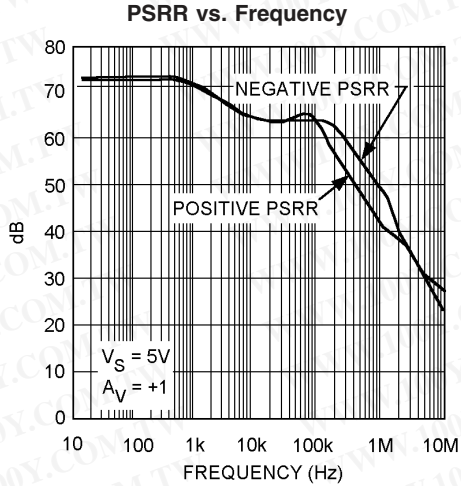
CMRR vs. Frequency



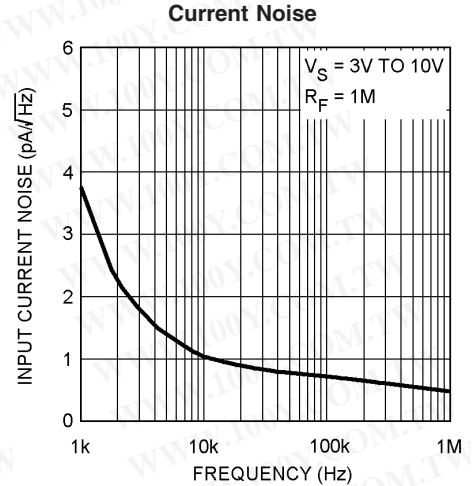
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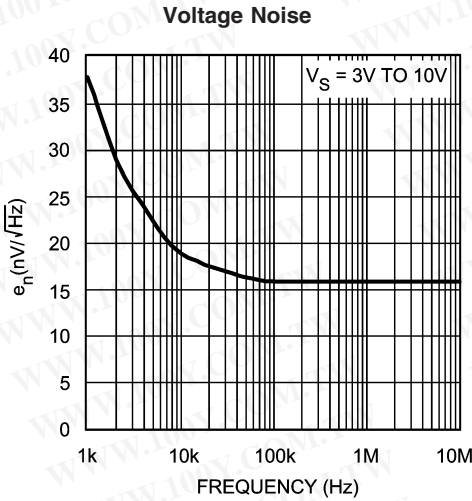
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20030217

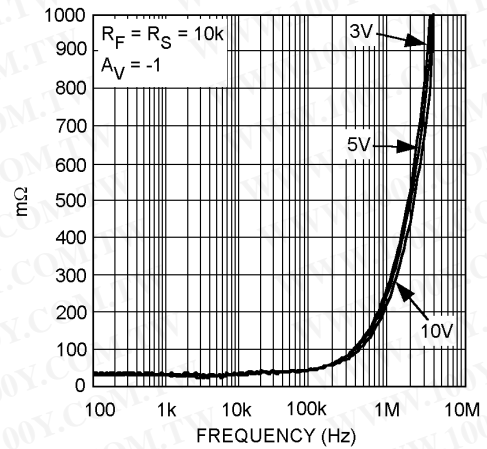


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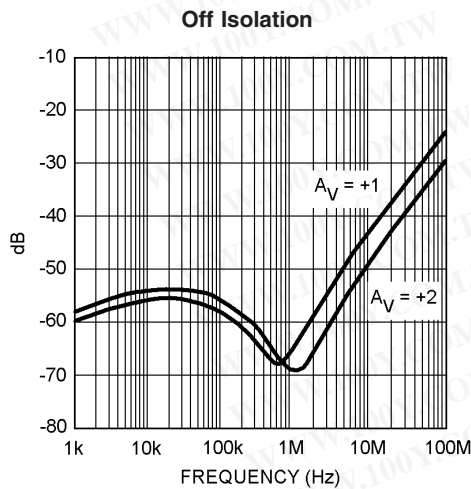


20030219

Closed Loop Output Resistance vs. Frequency

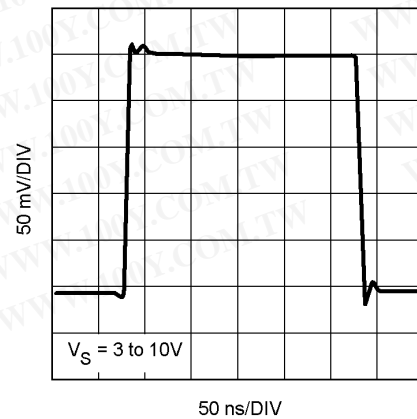


20030221



20030222

Small Signal Pulse Response ($A_V = +1$, $R_L = 2\text{k}$)

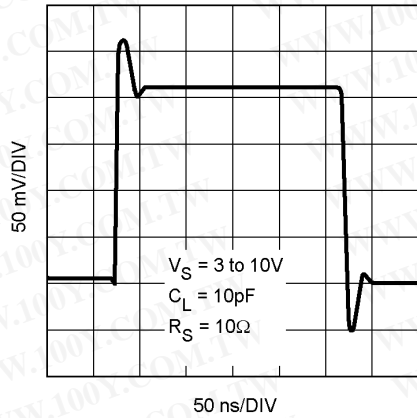


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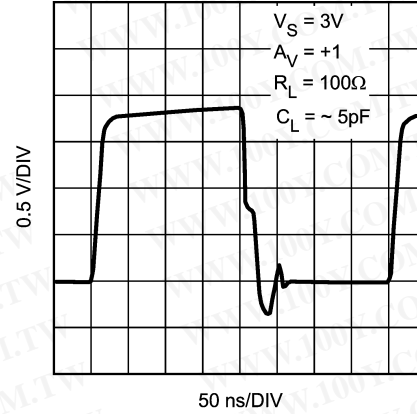
Typical Performance Characteristics At $T_J = 25^\circ\text{C}$, $V^+ = +2.5$, $V^- = -2.5\text{V}$, $R_F = 330\Omega$ for $A_V = +2$, $R_F = 1\text{k}\Omega$ for $A_V = -1$. Unless otherwise specified. (Continued)

Small Signal Pulse Response ($A_V = -1$)



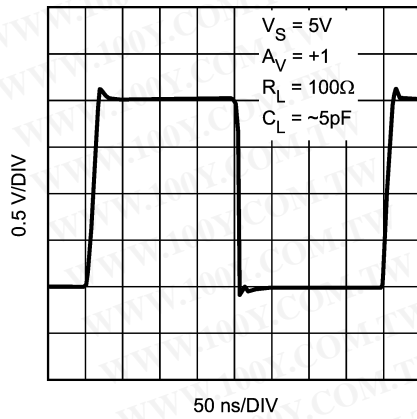
20030249

Large Signal Pulse Response ($R_L = 2\text{k}$)



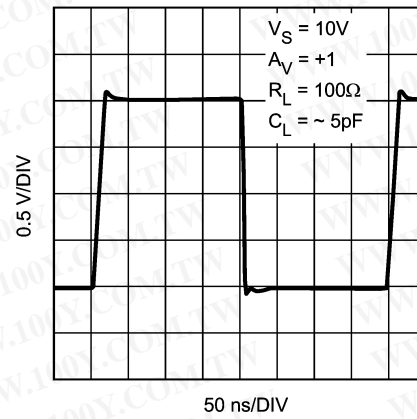
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Large Signal Pulse Response



20030227

Large Signal Pulse Response



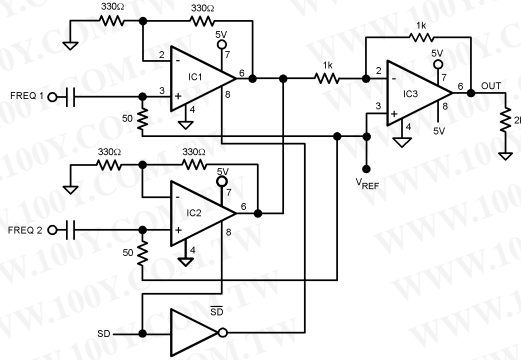
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Application Notes

MULTIPLEXING 5 AND 10MHz

The LMH6639 may be used to implement a circuit which multiplexes two signals of different frequencies. Three LMH6639 high speed op-amps are used in the circuit of *Figure 2* to accomplish the multiplexing function. Two LMH6639 are used to provide gain for the input signals, and the third device is used to provide output gain for the selected signal.

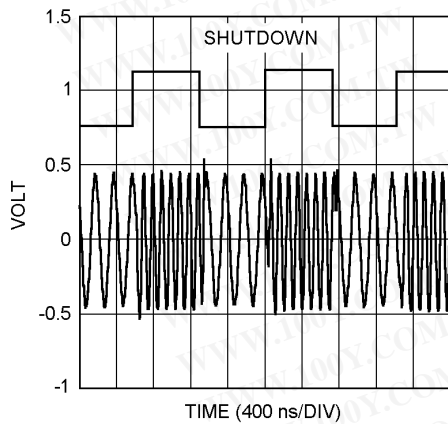


Note: Pin numbers pertain to SOIC-8 package

20030247

FIGURE 2. Multiplexer

Multiplexing signals "FREQ 1" and "FREQ 2" exhibit closed loop non-inverting gain of +2 each based upon identical 330Ω resistors in the gain setting positions of IC1 and IC2. The two multiplexing signals are combined at the input of IC3, which is the third LMH6639. This amplifier may be used as a unity gain buffer or may be used to set a particular gain for the circuit.



20030248

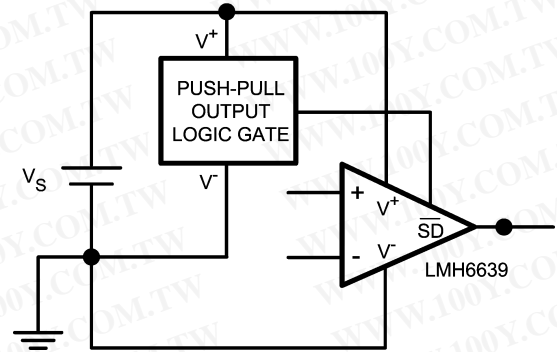
FIGURE 3. Switching between 5 and 10MHz

1k resistors are used to set an inverting gain of -1 for IC3 in the circuit of *Figure 2*. *Figure 3* illustrates the waveforms produced. The upper trace shows the switching waveform used to switch between the 5MHz and 10MHz multiplex signals. The lower trace shows the output waveform consisting of 5MHz and 10MHz signals corresponding to the high or low state of the switching signal.

In the circuit of *Figure 2*, the outputs of IC1 and IC2 are tied together such that their output impedances are placed in parallel at the input of IC3. The output impedance of the disabled amplifier is high compared both to the output impedance of the active amplifier and the 330Ω gain setting resistors. The closed loop output resistance for the LMH6639 is around 0.2Ω. Thus the active state amplifier output impedance dominates the input node to IC3, while the disabled amplifier is assured of a high level of suppression of unwanted signals which might be present at the output.

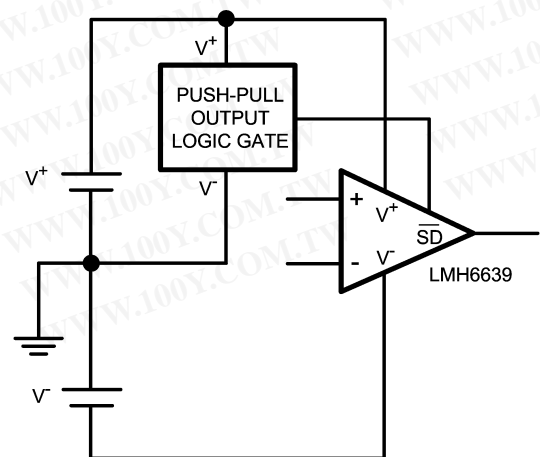
SHUTDOWN OPERATION

With \overline{SD} pin left floating, the device enters normal operation. However, since the \overline{SD} pin has high input impedance, it is best tied to V^+ for normal operation. This will avoid inadvertent shutdown due to capacitive pick-up from nearby nodes. LMH6639 will typically go into shutdown when \overline{SD} pin is more than 1.7V below V^+ , regardless of operating supplies. The \overline{SD} pin can be driven by push-pull or open collector (open drain) output logic. Because the LMH6639's shutdown is referenced to V^+ , interfacing to the shutdown logic is rather simple, for both single and dual supply operation, with either form of logic used. Typical configurations are shown in *Figure 4* and *Figure 5* below for push-pull output:



20030271

FIGURE 4. Shutdown Interface (Single Supply)



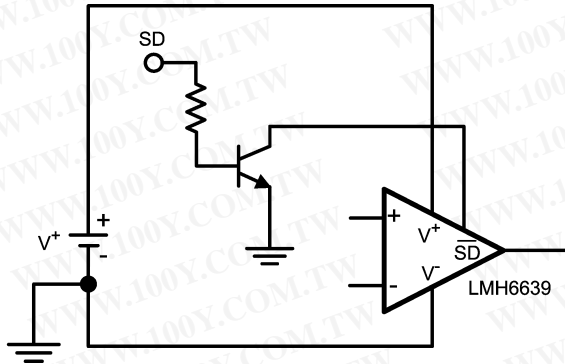
20030272

FIGURE 5. Shutdown Interface (Dual Supplies)

Common voltages for logic gates are +5V or +3V. To ensure proper power on/off with these supplies, the logic should be able to swing to 3.4V and 1.4V minimum, respectively.

Application Notes (Continued)

LMH6639's shutdown pin can also be easily controlled in applications where the analog and digital sections are operated at different supplies. *Figure 6* shows a configuration where a logic output, SD, can turn the LMH6639 on and off, independent of what supplies are used for the analog and the digital sections:



20030273

FIGURE 6. Shutdown Interface (Single Supply, Open Collector Logic)

The LMH6639 has an internal pull-up resistor on \overline{SD} such that if left un-connected, the device will be in normal operation. Therefore, no pull-up resistor is needed on this pin. Another common application is where the transistor in *Figure 6* above, would be internal to an open collector (open drain) logic gate; the basic connections will remain the same as shown.

PCB LAYOUT CONSIDERATION AND COMPONENTS SELECTION

Care should be taken while placing components on a PCB. All standard rules should be followed especially the ones for high frequency and/ or high gain designs. Input and output pins should be separated to reduce cross-talk, especially under high gain conditions. A groundplane will be helpful to avoid oscillations. In addition, a ground plane can be used to create micro-strip transmission lines for matching purposes. Power supply, as well as shutdown pin de-coupling will reduce cross-talk and chances of oscillations.

Another important parameter in working with high speed amplifiers is the component values selection. Choosing high value resistances reduces the cut-off frequency because of the influence of parasitic capacitances. On the other hand choosing the resistor values too low could "load down" the nodes and will contribute to higher overall power dissipation. Keeping resistor values at several hundreds of ohms up to several k Ω will offer good performance.

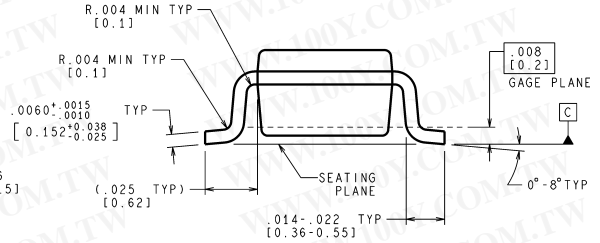
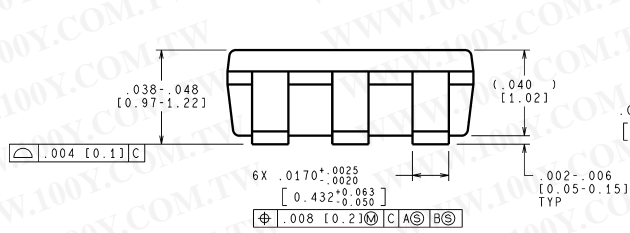
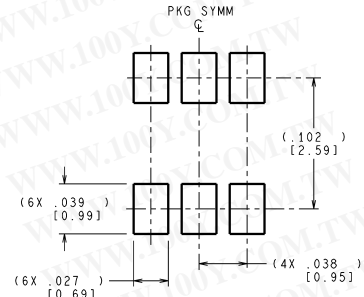
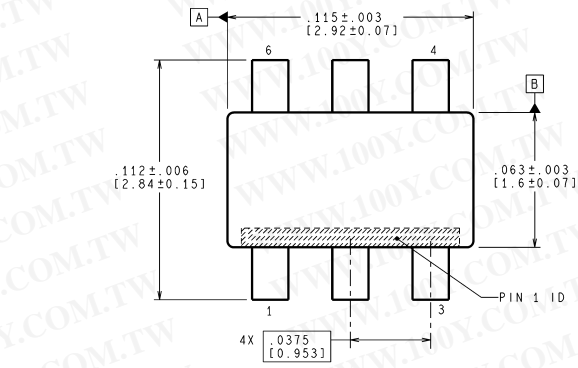
National Semiconductor suggests the following evaluation boards as a guide for high frequency layout and as an aid in device testing and characterization:

Device	Package	Evaluation Board PN
LMH6639MA	8-Pin SOIC	CLC730027
LMH6639MF	SOT23-6	CLC730116

These free evaluation boards are shipped when a device sample request is placed with National Semiconductor. For normal operation, tie the SD pin to V^+ .

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Physical Dimensions inches (millimeters) unless otherwise noted

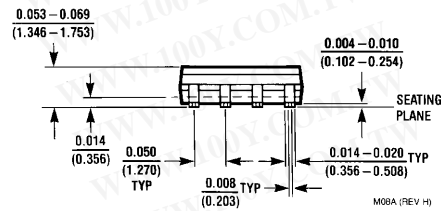
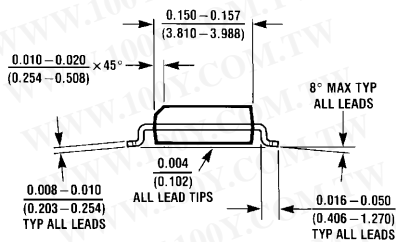
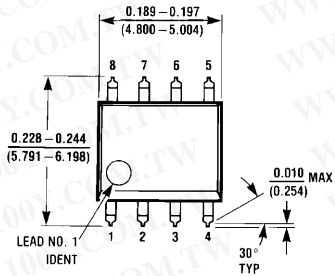


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 VALUES IN [] ARE MILLIMETERS

MF06A (Rev B)

6-Pin SOT23
NS Package Number MF06A

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8-Pin SOIC
NS Package Number M08A

Notes

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